## NSN 5962-01-359-5370

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-359-5370

view Offline at https://aerobasegroup.com/hist//3302-01-333-3370
Body Length:
0.740 inches
Body Width:
Between 0.380 inches and 0.420 inches
Body Height:
Between 0.090 inches and 0.130 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Disk drive unit
Features Provided:
Bidirectional and w/enable and w/disable and programmable and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Leaded chip carrier
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
26 input
Case Outline Source And Designator:
F-12 mil-m-38510
Current Rating Per Characteristic:
80.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 6.25 volts power source
Capitance Rating Per Characteristic:
10.00 input picofarads and 10.00 output picofarads
Time Rating Per Chacteristic:
200.00 nanoseconds access
Memory Device Type:
Eeprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

28 flat leads

## NSN 5962-01-359-5370

Memory Microcircuit - Page 2 of 2



_					
c	hο	JIF.		.ife:	
J			_	.II C.	

N/a

**Unit Of Measure:** 

--

Demilitarization:

No

Fiig:

A458a0